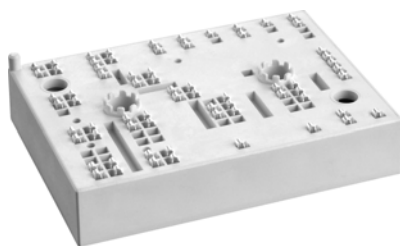


SKiiP 37AC12T4V1



MiniSKiiP® 3

SKiiP 37AC12T4V1

Features

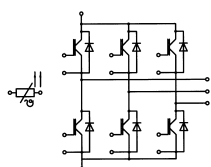
- Trench 4 IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised: File no. E63532

Typical Applications*

- Inverter up to 36 kVA
- Typical motor power 22 kW

Remarks

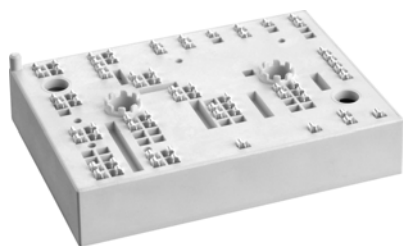
- Max. case temperature limited to $T_C=125^\circ\text{C}$
- Product reliability results valid for $T_J \leq 150^\circ\text{C}$ (recommended $T_{J,op} = -40 \dots +150^\circ\text{C}$)
- MiniSKiiP "Technical Explanations" and "Mounting Instructions" are part of the data sheet. Please refer to both documents for further information.



AC

Absolute Maximum Ratings				
Symbol	Conditions		Values	Unit
Inverter - IGBT				
V _{CES}	T _j = 25 °C		1200	V
I _C	λ _{paste} =0.8 W/(mK)	T _s = 25 °C	90	A
	T _j = 175 °C	T _s = 70 °C	73	A
I _C	λ _{paste} =2.5 W/(mK)	T _s = 25 °C	106	A
	T _j = 175 °C	T _s = 70 °C	86	A
I _{Cnom}			75	A
I _{CRM}	I _{CRM} = 3 x I _{Cnom}		225	A
V _{GES}			-20 ... 20	V
t _{psc}	V _{CC} = 800 V V _{GE} ≤ 15 V V _{CES} ≤ 1200 V	T _j = 150 °C	10	μs
T _j			-40 ... 175	°C
Inverse - Diode				
I _F	λ _{paste} =0.8 W/(mK)	T _s = 25 °C	83	A
	T _j = 175 °C	T _s = 70 °C	66	A
I _F	λ _{paste} =2.5 W/(mK)	T _s = 25 °C	95	A
	T _j = 175 °C	T _s = 70 °C	76	A
I _{Fnom}			75	A
I _{FRM}	I _{FRM} = 3 x I _{Fnom}		225	A
I _{FSM}	10 ms, sin 180°, T _j = 150 °C		430	A
T _j			-40 ... 175	°C
Module				
I _{t(RMS)}	T _{terminal} = 80 °C, 20 A per spring		160	A
T _{stg}			-40 ... 125	°C
V _{isol}	AC sinus 50 Hz, t = 1 min		2500	V

Characteristics						
Symbol	Conditions		min.	typ.	max.	Unit
Inverter - IGBT						
V _{CE(sat)}	I _C = 75 A	T _j = 25 °C		1.85	2.10	V
	V _{GE} = 15 V chipelevel	T _j = 150 °C		2.25	2.45	V
V _{CE0}	chipelevel	T _j = 25 °C		0.80	0.90	V
		T _j = 150 °C		0.70	0.80	V
r _{CE}	V _{GE} = 15 V	T _j = 25 °C		14	16	mΩ
	chipelevel	T _j = 150 °C		21	22	mΩ
V _{GE(th)}	V _{GE} = V _{CE} , I _C = 3 mA		5	5.8	6.5	V
I _{CES}	V _{GE} = 0 V, V _{CE} = 1200 V, T _j = 25 °C			0.1	0.3	mA
C _{ies}	V _{CE} = 25 V V _{GE} = 0 V	f = 1 MHz		4.40		nF
C _{oes}		f = 1 MHz		0.29		nF
C _{res}		f = 1 MHz		0.24		nF
Q _G	- 8 V...+ 15 V			425		nC
R _{Gint}	T _j = 25 °C			10		Ω
t _{d(on)}	V _{CC} = 600 V	T _j = 150 °C		145		ns
t _r	I _C = 75 A	T _j = 150 °C		45		ns
E _{on}	R _{G on} = 1 Ω	T _j = 150 °C		11.5		mJ
	R _{G off} = 1 Ω	T _j = 150 °C				
t _{d(off)}	di/dt _{on} = 1560 A/μs	T _j = 150 °C		350		ns
t _f	di/dt _{off} = 1180 A/μs	T _j = 150 °C		65		ns
E _{off}	V _{GE} = +15/-15 V	T _j = 150 °C		6.8		mJ
R _{th(j-s)}	per IGBT, λ _{paste} =0.8 W/(mK)			0.58		K/W
R _{th(j-s)}	per IGBT, λ _{paste} =2.5 W/(mK)			0.44		K/W



MiniSKiiP® 3

SKiiP 37AC12T4V1

Features

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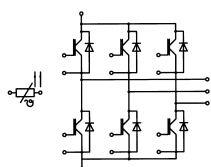
Typical Applications*

- Inverter up to 36 kVA
- Typical motor power 22 kW

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- Max. case temperature limited to $T_C=125^{\circ}\text{C}$
- Product reliability results valid for $T_J \leq 150^{\circ}\text{C}$ (recommended $T_{J,op} = -40 \dots +150^{\circ}\text{C}$)
- MiniSKiiP "Technical Explanations" and "Mounting Instructions" are part of the data sheet. Please refer to both documents for further information.

Characteristics						
Symbol	Conditions		min.	typ.	max.	Unit
Inverse - Diode						
V _F = V _{EC}	I _F = 75 A	T _j = 25 °C		2.17	2.49	V
	V _{GE} = 0 V chiplevel	T _j = 150 °C		2.11	2.42	V
V _{F0}	chiplevel	T _j = 25 °C		1.30	1.50	V
		T _j = 150 °C		0.90	1.10	V
r _F	chiplevel	T _j = 25 °C		12	13	mΩ
		T _j = 150 °C		16	18	mΩ
I _{RRM}	I _F = 75 A	T _j = 150 °C		99		A
Q _{rr}	di/dt _{off} = 2440 A/μs +15/-15	T _j = 150 °C		13.3		μC
E _{rr}	V _{CC} = 600 V	T _j = 150 °C		5.5		mJ
R _{th(j-s)}	per Diode, λ _{paste} =0.8 W/(mK)			0.75		K/W
R _{th(j-s)}	per Diode, λ _{paste} =2.5 W/(mK)			0.61		K/W
Module						
L _{CE}						nH
M _s	to heat sink		2		2.5	Nm
w				82		g
Temperature Sensor						
R ₁₀₀	T _r =100°C (R ₂₅ =1000Ω)			1670 ± 3%		Ω
R(T)	R(T)=1000Ω[1+A(T-25°C)+B(T-25°C) ²], A = 7.635*10 ⁻³ °C ⁻¹ , B = 1.731*10 ⁻⁵ °C ⁻²					



AC

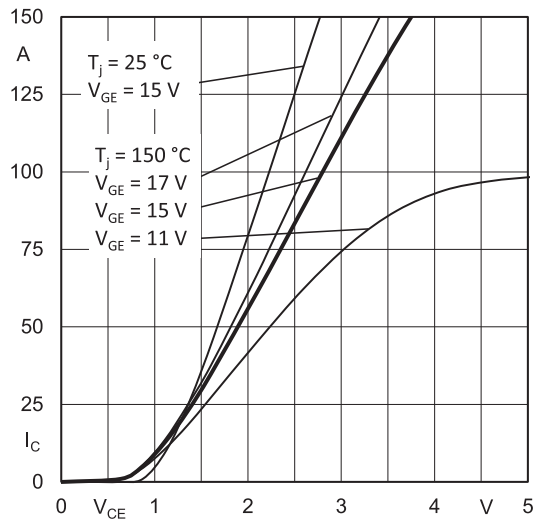


Fig. 1: Typ. output characteristic, inclusive $R_{CC'} + E_{E'}$

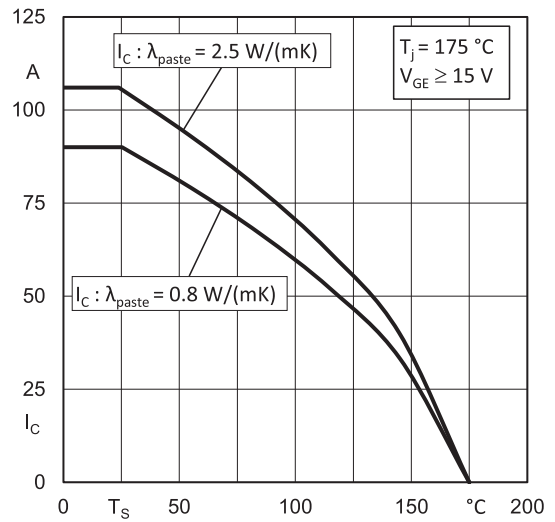


Fig. 2: Rated current vs. temperature $I_C = f(T_s)$

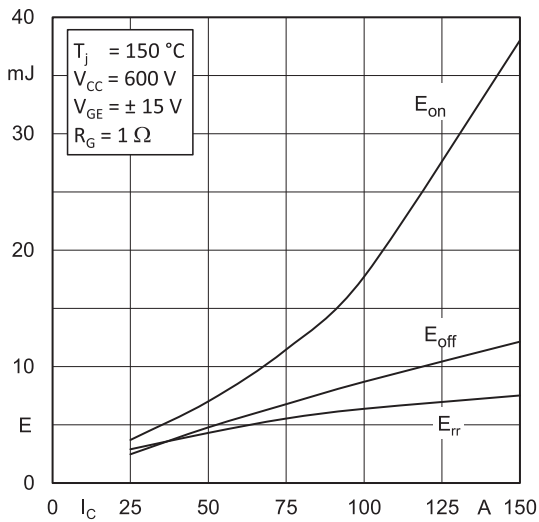


Fig. 3: Typ. turn-on /-off energy = $f(I_C)$

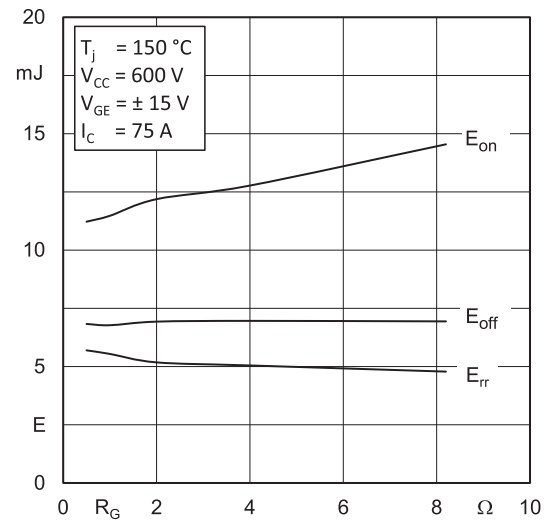


Fig. 4: Typ. turn-on /-off energy = $f(R_G)$

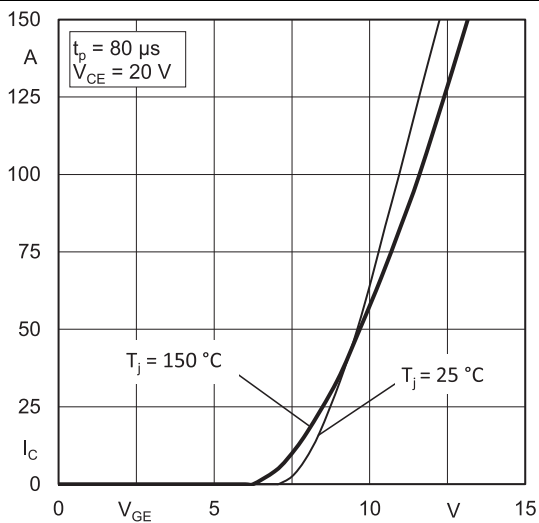


Fig. 5: Typ. transfer characteristic

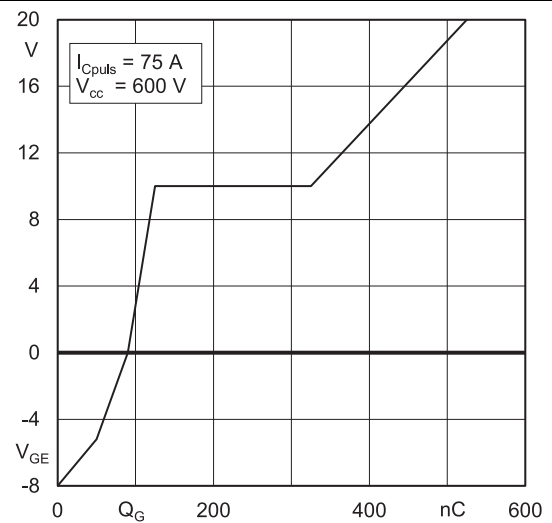


Fig. 6: Typ. gate charge characteristic

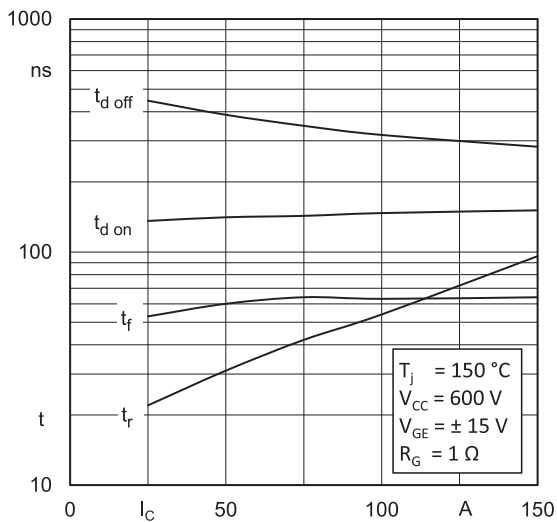


Fig. 7: Typ. switching times vs. I_C

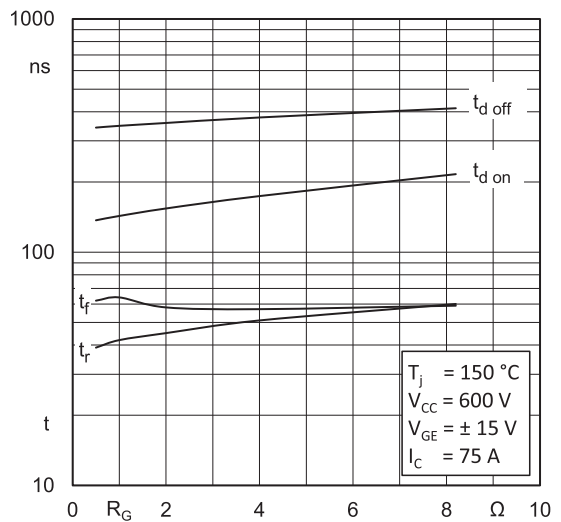


Fig. 8: Typ. switching times vs. gate resistor R_G

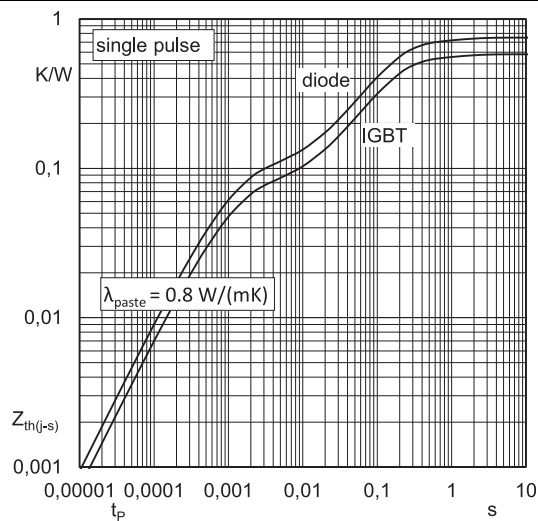


Fig. 9: Transient thermal impedance of IGBT and Diode

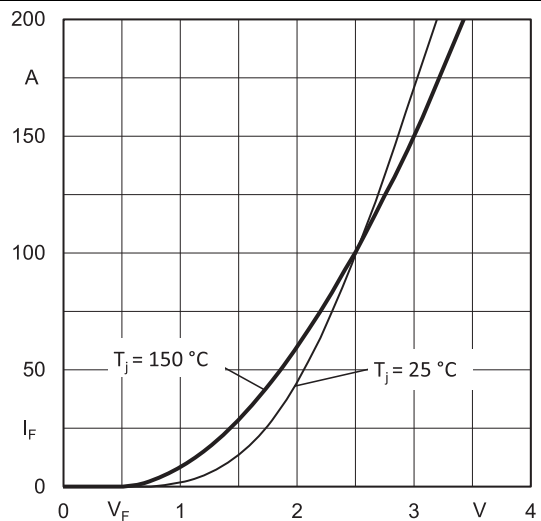


Fig. 10: CAL diode forward characteristic

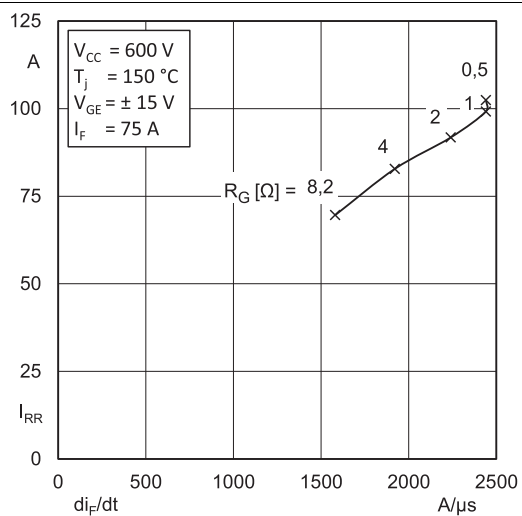


Fig. 11: Typ. CAL diode peak reverse recovery current

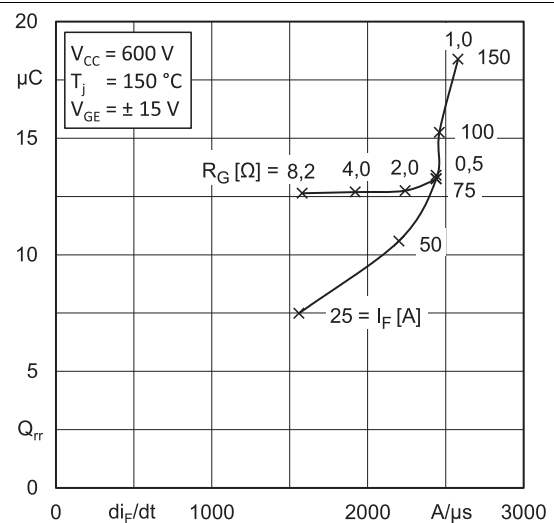
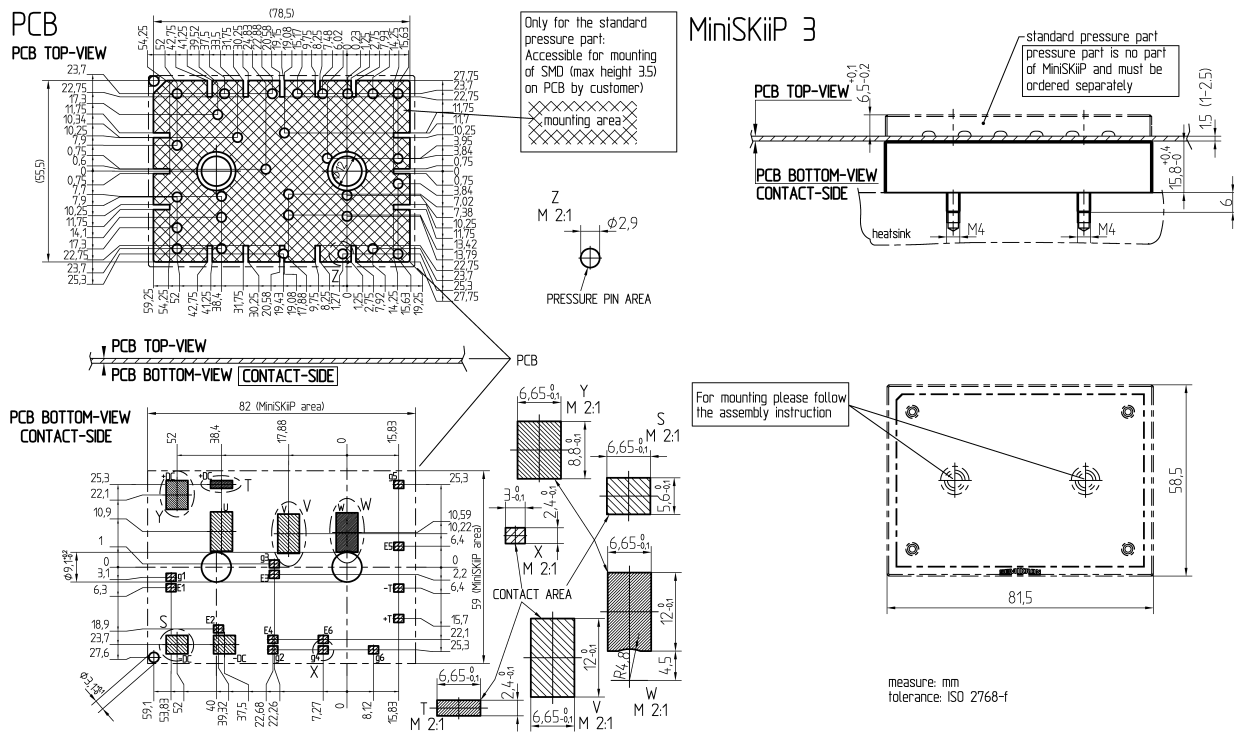
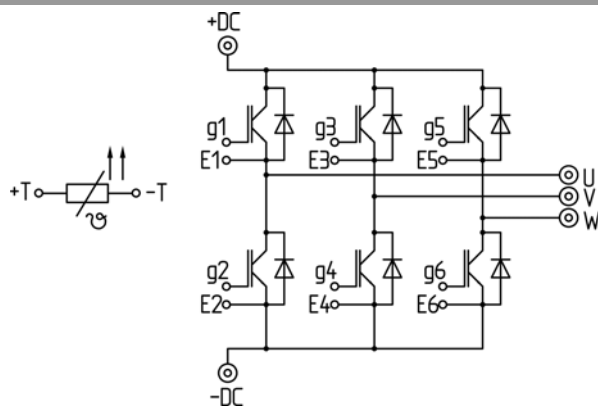


Fig. 12: Typ. CAL diode recovery charge



pinout, dimensions



⊙ power connector
• control connector

pinout

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

*IMPORTANT INFORMATION AND WARNINGS

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